

78LXX

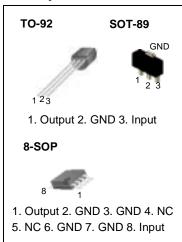
3-Terminal 0.1A Positive Voltage Regulator

Features

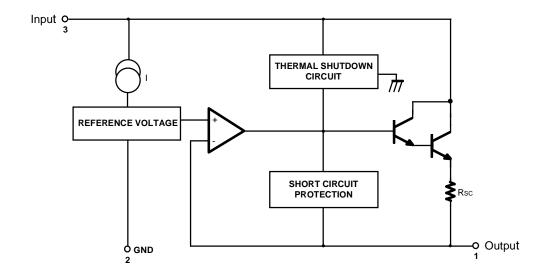
- Maximum Output Current of 100mA
- Output Voltage of 5V, 8V, 12V, 15V, 18V and 24V
- Thermal Overload Protection
- Short Circuit Current Limiting
- Output Voltage Offered in ±5% Tolerance

Description

The MC78LXXA/LM78LXXA/MC78L05AA series of fixed voltage monolithic integrated circuit voltage regulators are suitable for application that required supply current up to 100mA.



Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for V _O = 5V, 8V)	14.	30	V
(for V _O = 12V to 18V) (for V _O = 24V)	Vı	35 40	V
Operating Junction Temperature Range	TJ	0 ~ +150	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

Electrical Characteristics(MC78L05A/LM78L05A)

 $(V_I=10V,\ I_O=40mA,\ 0^{\circ}C\leq T_J\leq 125^{\circ}C,\ C_I=0.33\mu F,\ C_O=0.1\mu F,\ unless\ otherwise\ specified.\ (Note\ 1)$

Parameter		Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		4.8	5.0	5.2	V
Line Regulation (Not	te1)	4)/0	T _J = 25°C	7V ≤ V _I ≤ 20V	-	8	150	mV
,	,	ΔVΟ	1J = 25 C	8V ≤ V _I ≤ 20V	-	6	100	mV
Load Dogulation (No	sto 1)	ΔVο	T. 25°C	$1mA \le IO \le 100mA$	-	11	60	mV
Load Regulation (No	ote i)		T _J = 25°C	$1mA \le IO \le 40mA$	-	5.0	30	mV
			7V ≤ V _I ≤ 20V	$1mA \le IO \le 40mA$	-	-	5.25	V
Output Voltage		Vo	$7V \le V_I \le V_{MAX}$ (Note 2)	1mA ≤ I _O ≤ 70mA	4.75	-	5.25	V
Quiescent Current		IQ	T _J = 25°C		-	2.0	5.5	mA
Quiescent Current	With Line	ΔlQ	8V ≤VI ≤ 20V		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ Io ≤ 40 m	nA	-	-	0.1	mA
Output Noise Voltage VN T		$TA = 25^{\circ}C$, $10Hz \le f \le 100kHz$		-	40	-	μV/Vo	
Temperature Coefficient of V _O ΔV _O /ΔT		IO = 5mA		-	-0.65	-	mV/°C	
Ripple Rejection		RR	f = 120Hz, 8V ≤ V _I ≤ 18V, T _J = 25°C		41	80	-	dB
Dropout Voltage		VD	TJ = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Electrical Characteristics(MC78L08A) (Continued)

(VI = 14V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note 1)

Parameter		Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		7.7	8.0	8.3	V
Line Population (Note	51)	ΔVο	T _J = 25°C	10.5V ≤ V _I ≤ 23V	-	10	175	mV
Line Regulation (Note	5 1)	ΔνΟ	1J = 25 C	11V ≤ V _I ≤ 23V	-	8	125	mV
Load Population (Not	:01)	ΔVο	TJ = 25°C	$1mA \le IO \le 100mA$	-	15	80	mV
Load Regulation (Not	. e 1)	ΔνΟ		$1mA \le IO \le 40mA$	-	8.0	40	mV
			10.5V ≤ V _I ≤ 23V	$1mA \le IO \le 40mA$	7.6	-	8.4	V
Output Voltage		Vo	10.5V ≤ V _I ≤ VMAX (Note 2)	1mA ≤ I _O ≤ 70mA	7.6	-	8.4	V
Quiescent Current		lQ	T _J = 25°C		-	2.0	5.5	mA
Quiescent Current	With Line	ΔlQ	$11 \text{V} \leq \text{V}_{\text{I}} \leq 23 \text{V}$		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40m	$1mA \le IO \le 40mA$		-	0.1	mA
Output Noise Voltage		VN	T _A = 25°C, 10Hz ≤ f ≤100kHz		-	60	-	μV/Vo
Temperature Coefficient of VO		ΔV0/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Ripple Rejection RR		$f = 120Hz, 11V \le V_I \le 21V, T_J = 25^{\circ}C$		39	70	-	dB	
Dropout Voltage		VD	TJ = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Electrical Characteristics(MC78L12A/LM78L12A) (Continued)

(VI = 19V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note 1)

Parameter	Parameter Symbol Conditions		nditions	Min.	Тур.	Max.	Unit	
Output Voltage		Vo	T _J = 25°C		11.5	12	12.5	V
Line Regulation (Not	01)	ΔVΩ	T.j = 25°C	$14.5 \text{V} \leq \text{V}_{\text{I}} \leq 27 \text{V}$	-	20	250	mV
Line Regulation (Note	Ð1)	ΔνΟ	1J = 25°C	16V ≤ V _I ≤ 27V	-	15	200	mV
Load Degulation (No.	to1)	۸۱/۵	T.j = 25°C	$1mA \le IO \le 100mA$	-	20	100	mV
Load Regulation (No	le i)	ΔVΟ	1J = 25°C	$1mA \le IO \le 40mA$	-	10	50	mV
			14.5V ≤ V _I ≤ 27V	$1mA \le IO \le 40mA$	11.4	-	12.6	V
Output Voltage		Vo	14.5V ≤ V _I ≤ V _{MAX} (Note 2)	1mA ≤ I _O ≤ 70mA	11.4	-	12.6	V
Quiescent Current		lQ	T _J = 25°C		-	2.1	6.0	mA
Quiescent Current	With Line	ΔlQ	16V ≤ V _I ≤ 27V		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40m	A	-	-	0.1	mA
Output Noise Voltage		VN	T _A = 25°C, 10Hz ≤ f ≤ 100kHz		-	80	-	μV/Vo
Temperature Coefficient of Vo		ΔV0/ΔΤ	I _O = 5mA		-	-1.0	-	mV/°C
Ripple Rejection RR f =		$f = 120Hz, 15V \le VI \le 25V, TJ = 25^{\circ}C$		37	65	-	dB	
Dropout Voltage		VD	T _J = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $P_D \le 0.75W$.

Electrical Characteristics(MC78L15A) (Continued)

(VI = 23V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note 1)

Parameter		Symbol	Coi	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		14.4	15	15.6	V
Line Regulation (Note	51)	ΔVο	T _J = 25°C	17.5V ≤ V _I ≤ 30V	-	25	300	mV
Line Regulation (Note	- 1)	ΔνΟ	11 = 23 C	$20V \le V_I \le 30V$	-	20	250	mV
Load Regulation (Not	·o1)	ΔVο	T _J = 25°C	1mA ≤ I _O ≤ 100mA	-	25	150	mV
Load Negulation (Not	. c 1 <i>)</i>	ΔνΟ	11 = 23 C	$1mA \le IO \le 40mA$	-	12	75	mV
			17.5V ≤ V _I ≤ 30V	$1mA \le I_O \le 40mA$	14.25	-	15.75	V
Output Voltage		Vo	17.5V ≤ V _I ≤ VMAX (Note 2)	1mA ≤ I _O ≤ 70mA	14.25	-	15.75	V
Quiescent Current		lQ	T _J = 25°C		-	2.1	6.0	mA
Quiescent Current	With Line	ΔlQ	20V ≤ V _I ≤ 30V		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40mA		-	-	0.1	mA
Output Noise Voltage	Output Noise Voltage		T _A = 25°C, 10Hz ≤ f ≤ 100kHz		-	90	-	μV/Vo
Temperature Coefficient of Vo		ΔV0/ΔΤ	IO = 5mA		-	-1.3	-	mV/°C
Ripple Rejection		RR	RR		34	60	-	dB
Dropout Voltage		VD	TJ = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Electrical Characteristics(MC78L18A) (Continued)

(VI = 27V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note 1)

Parameter		Symbol	Coi	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		17.3	18	18.7	V
Line Regulation (Note	1)	ΔVΩ	T _J = 25°C	21V ≤ V _I ≤ 33V	-	145	300	mV
Line Regulation (Note	5 1)	ΔνΟ	1J = 25 C	22V ≤ V _I ≤ 33V	-	135	250	mV
Load Population (Not	·o1)	ΔVΩ	T _J = 25°C	1mA ≤ Io≤100mA	-	30	170	mV
Load Regulation (Not	.e i)	ΔνΟ	1J = 25 C	$1mA \le IO \le 40mA$	-	15	85	mV
			$21 \text{V} \leq \text{V}_{\text{I}} \leq 33 \text{V}$	$1mA \le IO \le 40mA$	17.1	-	18.9	V
Output Voltage		Vo	21V ≤ V _I ≤ VMAX (Note 2)	1mA ≤ I _O ≤ 70mA	17.1	-	18.9	V
Quiescent Current		lQ	T _J = 25°C		-	2.2	6.0	mA
Quiescent Current	With Line	ΔlQ	$21 \text{V} \leq \text{V}_{\text{I}} \leq 33 \text{V}$		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40mA		-	-	0.1	mA
Output Noise Voltage V _N T _A = 25°C,		T _A = 25°C, 10H;	z ≤ f ≤ 100kHz	-	150	-	μV/Vo	
Temperature Coefficient of VO ΔVo		ΔV0/ΔΤ	IO = 5mA		-	-1.8	-	mV/°C
Ripple Rejection		RR	f = 120Hz, 23V ≤ V _I ≤ 33V, T _J = 25°C		34	48	-	dB
Dropout Voltage		VD	TJ = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Electrical Characteristics(MC78L24A) (Continued)

(VI = 33V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note 1)

Parameter		Symbol	Coi	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		23	24	25	V
Line Regulation (Note	e1)	ΔVο	T _J = 25°C	27V ≤ V _I ≤ 38V	-	160	300	mV
,	,	ΔνΟ	1J = 25 C	28V ≤ V _I ≤ 38V	-	150	250	mV
Load Population (Not	:01)	ΔVΩ	T _J = 25°C	1mA ≤ IO ≤ 100mA	-	40	200	mV
Load Regulation (Not	.e i)	ΔνΟ	1J = 25 C	$1mA \le IO \le 40mA$	-	20	100	mV
			$27V \le V_I \le 38V$	$1mA \le IO \le 40mA$	22.8	-	25.2	V
Output Voltage		Vo	27V ≤ V _I ≤ VMAX (Note 2)	1mA ≤ I _O ≤ 70mA	22.8	-	25.2	V
Quiescent Current		lQ	T _J = 25°C		-	2.2	6.0	mA
Quiescent Current	With Line	ΔlQ	$28V \leq V_I \leq 38V$		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40m	A	-	-	0.1	mA
Output Noise Voltage V _N		VN	T _A = 25°C, 10Hz ≤ f ≤ 100kHz		-	200	-	μV/Vo
Temperature Coefficient of Vo		ΔV0/ΔΤ	IO = 5mA		-	-2.0	-	mV/°C
Ripple Rejection		RR	RR $f = 120$ Hz, 28 V \leq V $_{I} \leq 38$ V, $T_{J} = 25$ °C		34	45	-	dB
Dropout Voltage		VD	TJ = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for $V_O = 5V$, $8V$) (for $V_O = 12V$ to $18V$) (for $V_O = 24V$)	Vı	30 35 40	V V V
Operating Junction Temperature Range	TJ	0 ~ +150	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

Electrical Characteristics(MC78L05AA) (Continued)

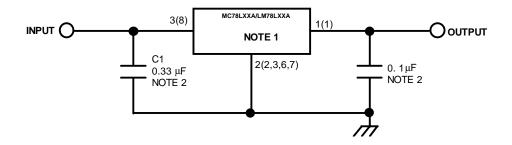
(VI = 10V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note 1)

Parameter		Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		4.9	5.0	5.1	V
Line Regulation (Not	te1)	۸۱/۵	TJ = 25°C	7V ≤ V _I ≤ 20V	-	8	150	mV
, ,	,	ΔVO	1J = 25 C	8V ≤ V _I ≤ 20V	-	6	100	mV
Load Regulation (No	sto1)	ΔVο	TJ = 25°C	$1mA \le IO \le 100mA$	-	11	50	mV
Load Regulation (NC	ne i)		1J = 25 C	$1mA \le IO \le 40mA$	-	5.0	25	mV
			7V ≤VI ≤20V	$1mA \le IO \le 40mA$	-	-	5.15	V
Output Voltage		Vo	$7V \le V_I \le V_{MAX}$ (Note 2)	1mA ≤ I _O ≤ 70mA	4.75	-	5.15	V
Quiescent Current		lQ	T _J = 25°C		-	2.0	5.5	mA
Quiescent Current	With Line	ΔlQ	8V ≤VI ≤ 20V		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40 m	nA	-	-	0.1	mA
Output Noise Voltage	е	VN	VN $T_A = 25^{\circ}C$, $10Hz \le f \le 100kHz$		-	40	-	μV/Vo
Temperature Coeffic	eient of Vo	ΔV0/ΔΤ	I _O = 5mA		-	-0.65	-	mV/°C
Ripple Rejection		RR	$f = 120Hz, 8V \le V_I \le 18V, T_J = 25^{\circ}C$		41	80	-	dB
Dropout Voltage		VD	TJ = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Typical Application



'()': 8SOP Type

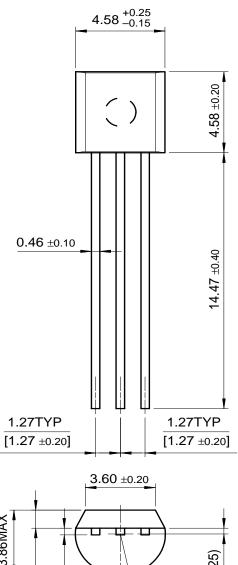
- 1. To specify an output voltage, substitute voltage value for "XX".
- 2. Bypass Capacitors are recommend for optimum stability and transient response and should be located as close as possible to the regulator

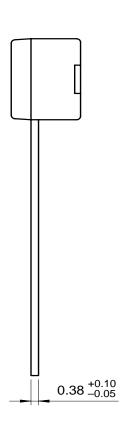
Mechanical Dimensions

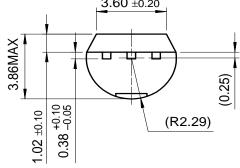
Package

Dimensions in millimeters

TO-92





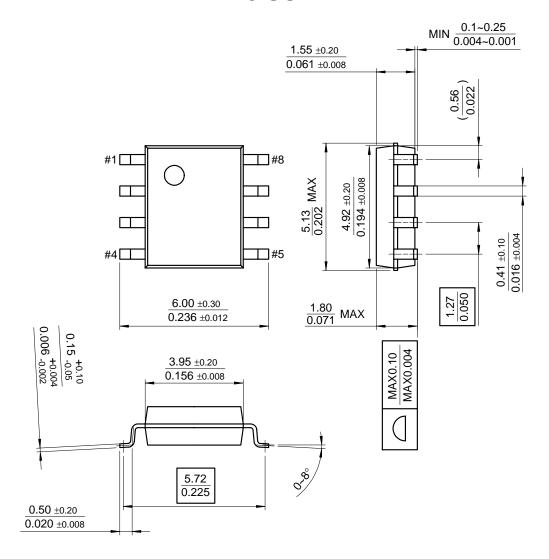


Mechanical Dimensions (Continued)

Package

Dimensions in millimeters

8-SOP

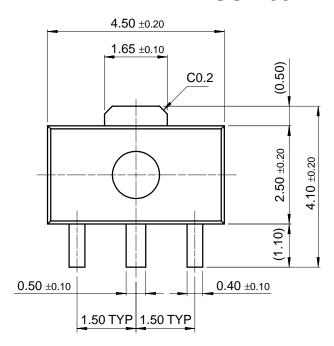


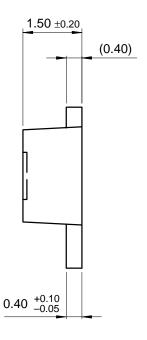
Mechanical Dimensions (Continued)

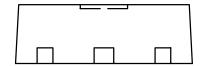
Package

Dimensions in millimeters

SOT-89







Ordering Information

Product Number	Package	Output Voltage Tolerance	Operating Temperature
LM78L05ACZ	TO-92 5%		0 ~ +125°C
LM78L12ACZ	10-92	5%	0 ~ +125°C
Product Number	Package	Output Voltage Tolerance	Operating Temperature
MC78L05ACP			
MC78L08ACP			
MC78L12ACP	TO-92		
MC78L15ACP	10-92		
MC78L18ACP			
MC78L24ACP		5%	
MC78L05ACD		5%	0 ~ +125°C
MC78L08ACD	8-SOP		0 1120 0
MC78L12ACD			
MC78L05ACH			
MC78L08ACH	SOT-89		
MC78L12ACH			
MC78L05AACP	TO-92	2%	

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.